Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-396-3683

G	lass
0	verall Length:
0.	350 inches
Т	erminal Length:
0.	975 inches
0	verall Diameter:
0.	145 inches
Μ	lounting Method:
Т	erminal
F	eatures Provided:
Н	ermetically sealed case
S	emiconductor Material:
S	ilicon
V	oltage Rating In Volts Per Characteristic:
6	00.0 reverse voltage, peak
С	urrent Rating Per Characteristic:
3.	00 amperes forward current, average absolute
Μ	aximum Operating Tempurature Per Measurement Point:
1	75.0 degrees celsius ambient air
T	erminal Type And Quantity:
2	uninsulated wire lead
S	helf Life:
Ν	/a
U	nit Of Measure:
D	emilitarization:
Ν	0
F	iig: